

HIGH POWER PNP SILICON POWER TRANSISTORS

...designed for use in general-purpose amplifier and switching application .

FEATURES:

- * Recommend for 60 W High Fiderity Audio Frequency Amplifier Output stage
- * Complementary to 2SC2837

PNP 2SA1186

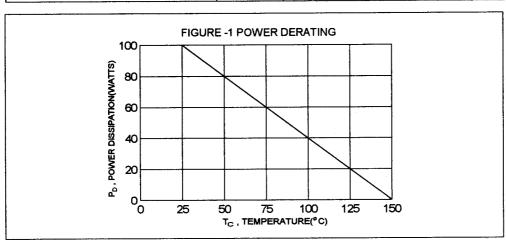
10 AMPERE POWER TRANASISTOR 150 VOLTS 100 WATTS

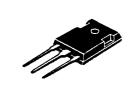
MAXIMUM RATINGS

Characteristic	Symbol	2SA1186	Unit
Collector-Emitter Voltage	V _{CEO}	150	V
Collector-Base Voltage	V _{сво}	150	V
Emitter-Base Voltage	V _{EBO}	5.0	V
Collector Current - Continuous - Peak	I _C	10 15	A
Base current	l _B	2.0	А
Total Power Dissipation @T _C = 25°C Derate above 25°C	P _D	100 0.8	W/°C
Operating and Storage Junction Temperature Range	T _J ,T _{STG}	-55 to +150	°C

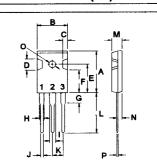
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance Junction to Case	Rθjc	1.25	°C/W





TO-247(3P)



PIN 1.BASE 2.COLLECTOR 3.EMITTER

DIM	MILLIMETERS				
ואוט	MIN	MAX			
Α	20.63	22.38			
В	15.38	16.20			
С	1.90	2.70			
D	5.10	6.10			
E	14.81	15.22			
F	11.72	12.84			
G	4.20	4.50			
Н	1.82	2.46			
1	2.92	3.23			
J	0.89	1.53			
K	5.26	5.66			
L	18.50	21.50			
M	4.68	5.36			
N	2.40	2.80			
0	3.25	3.65			
P	0.55	0.70			

Unit

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic

OFF CHARACTERISTICS				
Collector-Emitter Breakdown Voltage (I _C = 25 mA, I _B = 0)	V _{(BR)CEO}	150		V
Collector Cutoff Current (V _{CB} = 150 V, I _E = 0)	I _{CBO}		100	uA
Emitter Cutoff Current (V _{EB} = 5.0 V, I _C = 0)	I _{EBO}		100	uA

Symbol

Min

Max

ON CHARACTERISTICS (1)

DC Current Gain (I _C = 3.0 A, V _{CE} = 4.0 V)	hFE	30		
Collector-Emitter Saturation Voltage (I _C = 5.0 A, I _B = 500 mA)	V _{CE(sat)}		2.0	V

DYNAMIC CHARACTERISTICS

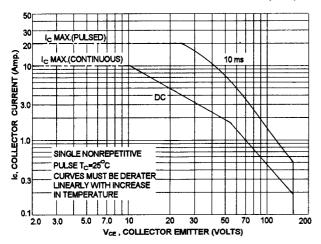
Current-Gain-Bandwidth Product	f _T		MHz
(I _C = 1.0 A, V _{CE} = 12 V, f = 1.0 MHz)	•	10	

SWITCHING CHARATERISTICS

Turn-on Time	V _{cc} = 60 V, I _c = 5.0 A	t on	0.40(typ)	us
Storage Time	I _{B1} = -I _{B2} = 0.5 A R. =12 ohm	ts	1.60(typ)	us
Fall Time	KL-12 Onin	t _f	0.50(typ)	us

⁽¹⁾ Pulse Test: Pulse Width =300 us, Duty Cycle $\leq 2.0\%$

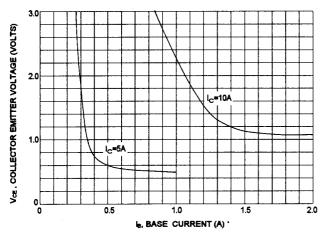
ACTIVE REGION SAFE OPERATING AREA (SOA)



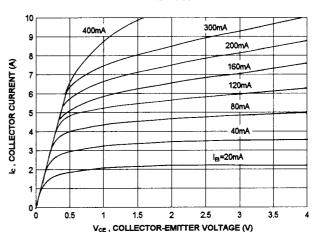
There are two limitation on the power handling ability of a transistor:average junction temperature and second breakdown safe operating area curves indicate $I_{\text{C}^{-}}V_{\text{CE}}$ limits of the transistor that must be observed for reliable operation i.e., the transistor must not be subjected to greater dissipation than curves indicate.

The data of SOA curve is base on $T_{J(PK)}$ =150 °C; T_C is variable depending on conditions. second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(PK)}$ ≤150°C,At high case temperatures, thermal limitation will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

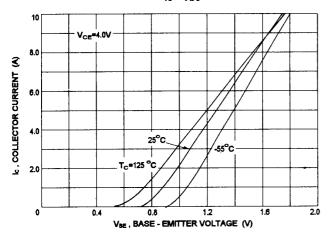




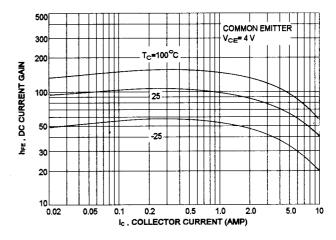




lc - Vbe



DC CURRENT GAIN





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